CPH3351



Features

- Low On-Resistance
- 4V Drive
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS Compliance

Specifications

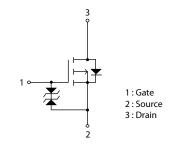
Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Value	Unit
Drain to Source Voltage	VDSS	-60	V
Gate to Source Voltage	V _{GSS}	±20	V
Drain Current (DC)	ID	-1.8	А
Drain Current (Pulse) PW ≤ 10μs, duty cycle ≤ 1%	IDP	-7.2	A
Power Dissipation When mounted on ceramic substrate (900mm ² × 0.8mm)	PD	1.0	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C



VDSS	R _{DS} (on) Max	ID Max
	250mΩ@ –10V	
-60V	330mΩ@ –4.5V	-1.8A
	350mΩ@ –4V	



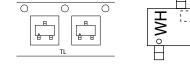


Packing Type : TL



Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm ² × 0.8mm)	R _{θJA}	125	°C/W



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION

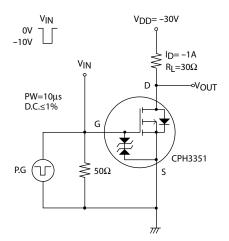
See detailed ordering and shipping information on page 5 of this data sheet.

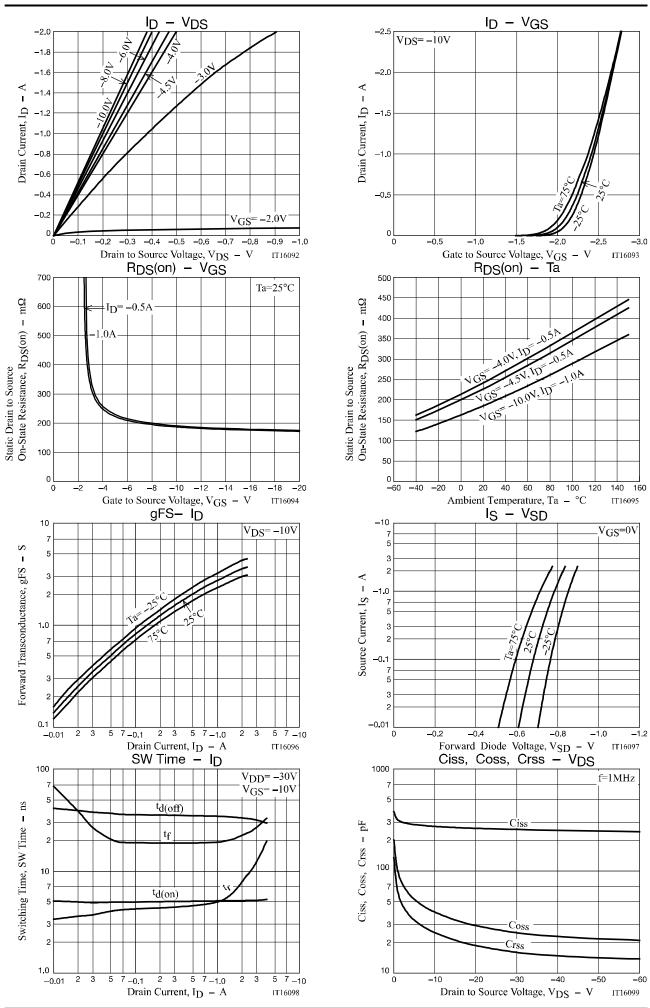
Electrical Characteristics at $Ta = 25^{\circ}C$

Parameter	Querrada a l			Value		
	Symbol	Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _{GS} =0V	-60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-60V, V _{GS} =0V			-1	μA
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μA
Gate Threshold Voltage	V _{GS} (th)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transconductance	9FS	V _{DS} =-10V, I _D =-1A		2.7		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =-1A, V _{GS} =-10V		190	250	mΩ
	R _{DS} (on)2	I _D =-0.5A, V _{GS} =-4.5V		235	330	mΩ
	R _{DS} (on)3	I _D =-0.5A, V _{GS} =-4V		250	350	mΩ
Input Capacitance	Ciss	V _{DS} =-20V, f=1MHz		262		pF
Output Capacitance	Coss			29		pF
Reverse Transfer Capacitance	Crss			19		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		5.1		ns
Rise Time	tr			5.4		ns
Turn-OFF Delay Time	t _d (off)			34		ns
Fall Time	tf	1		19		ns
Total Gate Charge	Qg	V _{DS} =-30V, V _{GS} =-10V, I _D =-1.8A		6.0		nC
Gate to Source Charge	Qgs			0.83		nC
Gate to Drain "Miller" Charge	Qgd	1		1.3		nC
Forward Diode Voltage	V _{SD}	I _S =-1.8A, V _{GS} =0V		-0.82	-1.2	V

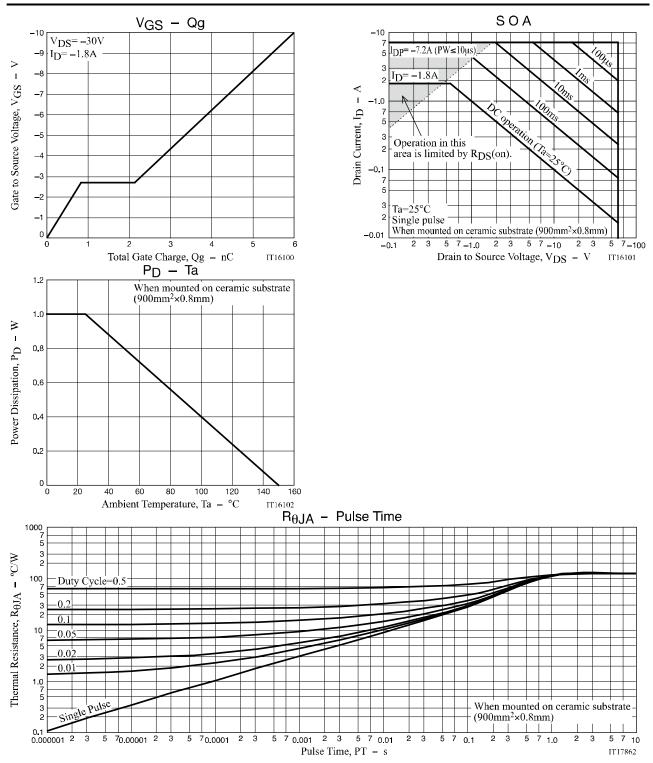
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit





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Package Dimensions

CPH3351-TL-H / CPH3351-TL-W

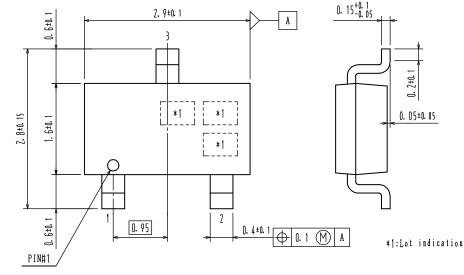
CPH3

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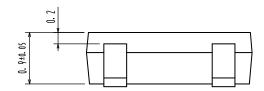
unit : mm

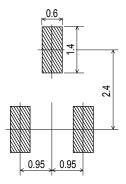
- 1 : Gate
- 2 : Source

3 : Drain



Recommended Soldering Footprint





ORDERING INFORMATION

Device	Package	Shipping	Note	
CPH3351-TL-H	CPH3, SC-59	3,000 pcs. / Tape & Reel	Pb-Free and	
CPH3351-TL-W	SOT-23, TO-236	3,000 pcs. / Tape & Reel	Halogen Free	

Note on usage : Since the CPH3351 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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